# E · ) (Lattice Semiconductor Corporation - LCMXO3LF-1300E-5MG256C Datasheet



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#### Understanding <u>Embedded - FPGAs (Field</u> <u>Programmable Gate Array)</u>

Embedded - FPGAs, or Field Programmable Gate Arrays, are advanced integrated circuits that offer unparalleled flexibility and performance for digital systems. Unlike traditional fixed-function logic devices, FPGAs can be programmed and reprogrammed to execute a wide array of logical operations, enabling customized functionality tailored to specific applications. This reprogrammability allows developers to iterate designs quickly and implement complex functions without the need for custom hardware.

#### **Applications of Embedded - FPGAs**

The versatility of Embedded - FPGAs makes them indispensable in numerous fields. In telecommunications.

#### Details

Product Status	Active
Number of LABs/CLBs	160
Number of Logic Elements/Cells	1280
Total RAM Bits	65536
Number of I/O	206
Number of Gates	-
Voltage - Supply	1.14V ~ 1.26V
Mounting Type	Surface Mount
Operating Temperature	0°C ~ 85°C (TJ)
Package / Case	256-VFBGA
Supplier Device Package	256-CSFBGA (9x9)
Purchase URL	https://www.e-xfl.com/product-detail/lattice-semiconductor/lcmxo3lf-1300e-5mg256c

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### Figure 2-8. sysMEM Memory Primitives





Port Name	Description	Active State
CLK	Clock	Rising Clock Edge
CE	Clock Enable	Active High
OCE <sup>1</sup>	Output Clock Enable	Active High
RST	Reset	Active High
BE <sup>1</sup>	Byte Enable	Active High
WE	Write Enable	Active High
AD	Address Bus	_
DI	Data In	_
DO	Data Out	_
CS	Chip Select	Active High
AFF	FIFO RAM Almost Full Flag	_
FF	FIFO RAM Full Flag	_
AEF	FIFO RAM Almost Empty Flag	_
EF	FIFO RAM Empty Flag	_
RPRST	FIFO RAM Read Pointer Reset	_

### Table 2-6. EBR Signal Descriptions

1. Optional signals.

2. For dual port EBR primitives a trailing 'A' or 'B' in the signal name specifies the EBR port A or port B respectively.

3. For FIFO RAM mode primitive, a trailing 'R' or 'W' in the signal name specifies the FIFO read port or write port respectively.

4. For FIFO RAM mode primitive FULLI has the same function as CSW(2) and EMPTYI has the same function as CSR(2).

In FIFO mode, CLKW is the write port clock, CSW is the write port chip select, CLKR is the read port clock, CSR is the read port clock, CSR is the read port clock.

The EBR memory supports three forms of write behavior for single or dual port operation:

- 1. **Normal** Data on the output appears only during the read cycle. During a write cycle, the data (at the current address) does not appear on the output. This mode is supported for all data widths.
- 2. Write Through A copy of the input data appears at the output of the same port. This mode is supported for all data widths.
- 3. Read-Before-Write When new data is being written, the old contents of the address appears at the output.

#### **FIFO Configuration**

The FIFO has a write port with data-in, CEW, WE and CLKW signals. There is a separate read port with data-out, RCE, RE and CLKR signals. The FIFO internally generates Almost Full, Full, Almost Empty and Empty Flags. The Full and Almost Full flags are registered with CLKW. The Empty and Almost Empty flags are registered with CLKR. Table 2-7 shows the range of programming values for these flags.

#### Table 2-7. Programmable FIFO Flag Ranges

Flag Name	Programming Range
Full (FF)	1 to max (up to 2 <sup>N</sup> -1)
Almost Full (AF)	1 to Full-1
Almost Empty (AE)	1 to Full-1
Empty (EF)	0

N = Address bit width.

The FIFO state machine supports two types of reset signals: RST and RPRST. The RST signal is a global reset that clears the contents of the FIFO by resetting the read/write pointer and puts the FIFO flags in their initial reset



### **Output Register Block**

The output register block registers signals from the core of the device before they are passed to the sysIO buffers.

### Left, Top, Bottom Edges

In SDR mode, D0 feeds one of the flip-flops that then feeds the output. The flip-flop can be configured as a D-type register or latch.

In DDR generic mode, D0 and D1 inputs are fed into registers on the positive edge of the clock. At the next falling edge the registered D1 input is registered into the register Q1. A multiplexer running off the same clock is used to switch the mux between the outputs of registers Q0 and Q1 that will then feed the output.

Figure 2-12 shows the output register block on the left, top and bottom edges.

Figure 2-12. MachXO3L/LF Output Register Block Diagram (PIO on the Left, Top and Bottom Edges)



### Tri-state Register Block

The tri-state register block registers tri-state control signals from the core of the device before they are passed to the sysIO buffers. The block contains a register for SDR operation. In SDR, TD input feeds one of the flip-flops that then feeds the output.



### sysIO Buffer

Each I/O is associated with a flexible buffer referred to as a sysIO buffer. These buffers are arranged around the periphery of the device in groups referred to as banks. The sysIO buffers allow users to implement a wide variety of standards that are found in today's systems including LVCMOS, TTL, PCI, LVDS, BLVDS, MLVDS and LVPECL.

Each bank is capable of supporting multiple I/O standards. In the MachXO3L/LF devices, single-ended output buffers, ratioed input buffers (LVTTL, LVCMOS and PCI), differential (LVDS) input buffers are powered using I/O supply voltage ( $V_{CCIO}$ ). Each sysIO bank has its own  $V_{CCIO}$ .

MachXO3L/LF devices contain three types of sysIO buffer pairs.

### 1. Left and Right sysIO Buffer Pairs

The sysIO buffer pairs in the left and right banks of the device consist of two single-ended output drivers and two single-ended input buffers (for ratioed inputs such as LVCMOS and LVTTL). The I/O pairs on the left and right of the devices also have differential input buffers.

### 2. Bottom sysIO Buffer Pairs

The sysIO buffer pairs in the bottom bank of the device consist of two single-ended output drivers and two single-ended input buffers (for ratioed inputs such as LVCMOS and LVTTL). The I/O pairs on the bottom also have differential input buffers. Only the I/Os on the bottom banks have programmable PCI clamps and differential input termination. The PCI clamp is enabled after  $V_{CC}$  and  $V_{CCIO}$  are at valid operating levels and the device has been configured.

### 3. Top sysIO Buffer Pairs

The sysIO buffer pairs in the top bank of the device consist of two single-ended output drivers and two singleended input buffers (for ratioed inputs such as LVCMOS and LVTTL). The I/O pairs on the top also have differential I/O buffers. Half of the sysIO buffer pairs on the top edge have true differential outputs. The sysIO buffer pair comprising of the A and B PIOs in every PIC on the top edge have a differential output driver.

### Typical I/O Behavior During Power-up

The internal power-on-reset (POR) signal is deactivated when  $V_{CC}$  and  $V_{CCIO0}$  have reached  $V_{PORUP}$  level defined in the Power-On-Reset Voltage table in the DC and Switching Characteristics section of this data sheet. After the POR signal is deactivated, the FPGA core logic becomes active. It is the user's responsibility to ensure that all  $V_{CCIO}$  banks are active with valid input logic levels to properly control the output logic states of all the I/O banks that are critical to the application. The default configuration of the I/O pins in a blank device is tri-state with a weak pulldown to GND (some pins such as PROGRAMN and the JTAG pins have weak pull-up to  $V_{CCIO}$  as the default functionality). The I/O pins will maintain the blank configuration until  $V_{CC}$  and  $V_{CCIO}$  (for I/O banks containing configuration I/Os) have reached  $V_{PORUP}$  levels at which time the I/Os will take on the user-configured settings only after a proper download/configuration.

There are various ways a user can ensure that there are no spurious signals on critical outputs as the device powers up. These are discussed in more detail in TN1280, MachXO3 sysIO Usage Guide.

### **Supported Standards**

The MachXO3L/LF sysIO buffer supports both single-ended and differential standards. Single-ended standards can be further subdivided into LVCMOS, LVTTL, and PCI. The buffer supports the LVTTL, PCI, LVCMOS 1.2 V, 1.5 V, 1.8 V, 2.5 V, and 3.3 V standards. In the LVCMOS and LVTTL modes, the buffer has individually configurable options for drive strength, bus maintenance (weak pull-up, weak pull-down, bus-keeper latch or none) and open drain. BLVDS, MLVDS and LVPECL output emulation is supported on all devices. The MachXO3L/LF devices support on-chip LVDS output buffers on approximately 50% of the I/Os on the top bank. Differential receivers for LVDS, BLVDS, MLVDS and LVPECL are supported on all banks of MachXO3L/LF devices. PCI support is provided in the bottom bank of the MachXO3L/LF devices. Table 2-11 summarizes the I/O characteristics of the MachXO3L/LF PLDs.



# Figure 2-15. MachXO3L/LF-1300 in 256 Ball Packages, MachXO3L/LF-2100, MachXO3L/LF-4300, MachXO3L/LF-6900 and MachXO3L/LF-9400 Banks



Figure 2-16. MachXO3L/LF-640 and MachXO3L/LF-1300 Banks





There are some limitations on the use of the hardened user SPI. These are defined in the following technical notes:

- TN1087, Minimizing System Interruption During Configuration Using TransFR Technology (Appendix B)
- TN1293, Using Hardened Control Functions in MachXO3 Devices

### Figure 2-19. SPI Core Block Diagram



Table 2-15 describes the signals interfacing with the SPI cores.

Table 2-15. SPI Core Signal Description

Signal Name	I/O	Master/Slave	Description
spi_csn[0]	0	Master	SPI master chip-select output
spi_csn[17]	0	Master	Additional SPI chip-select outputs (total up to eight slaves)
spi_scsn	I	Slave	SPI slave chip-select input
spi_irq	0	Master/Slave	Interrupt request
spi_clk	I/O	Master/Slave	SPI clock. Output in master mode. Input in slave mode.
spi_miso	I/O	Master/Slave	SPI data. Input in master mode. Output in slave mode.
spi_mosi	I/O	Master/Slave	SPI data. Output in master mode. Input in slave mode.
sn	I	Slave	Configuration Slave Chip Select (active low), dedicated for selecting the Con- figuration Logic.
cfg_stdby	0	Master/Slave	Stand-by signal – To be connected only to the power module of the MachXO3L/LF device. The signal is enabled only if the "Wakeup Enable" feature has been set within the EFB GUI, SPI Tab.
cfg_wake	0	Master/Slave	Wake-up signal – To be connected only to the power module of the MachXO3L/LF device. The signal is enabled only if the "Wakeup Enable" feature has been set within the EFB GUI, SPI Tab.



### **Configuration and Testing**

This section describes the configuration and testing features of the MachXO3L/LF family.

### IEEE 1149.1-Compliant Boundary Scan Testability

All MachXO3L/LF devices have boundary scan cells that are accessed through an IEEE 1149.1 compliant test access port (TAP). This allows functional testing of the circuit board, on which the device is mounted, through a serial scan path that can access all critical logic nodes. Internal registers are linked internally, allowing test data to be shifted in and loaded directly onto test nodes, or test data to be captured and shifted out for verification. The test access port consists of dedicated I/Os: TDI, TDO, TCK and TMS. The test access port shares its power supply with  $V_{CCIO}$  Bank 0 and can operate with LVCMOS3.3, 2.5, 1.8, 1.5, and 1.2 standards.

For more details on boundary scan test, see AN8066, Boundary Scan Testability with Lattice sysIO Capability and TN1087, Minimizing System Interruption During Configuration Using TransFR Technology.

### **Device Configuration**

All MachXO3L/LF devices contain two ports that can be used for device configuration. The Test Access Port (TAP), which supports bit-wide configuration and the sysCONFIG port which supports serial configuration through I<sup>2</sup>C or SPI. The TAP supports both the IEEE Standard 1149.1 Boundary Scan specification and the IEEE Standard 1532 In-System Configuration specification. There are various ways to configure a MachXO3L/LF device:

- 1. Internal NVCM/Flash Download
- 2. JTAG
- 3. Standard Serial Peripheral Interface (Master SPI mode) interface to boot PROM memory
- 4. System microprocessor to drive a serial slave SPI port (SSPI mode)
- 5. Standard I<sup>2</sup>C Interface to system microprocessor

Upon power-up, the configuration SRAM is ready to be configured using the selected sysCONFIG port. Once a configuration port is selected, it will remain active throughout that configuration cycle. The IEEE 1149.1 port can be activated any time after power-up by sending the appropriate command through the TAP port. Optionally the device can run a CRC check upon entering the user mode. This will ensure that the device was configured correctly.

The sysCONFIG port has 10 dual-function pins which can be used as general purpose I/Os if they are not required for configuration. See TN1279, MachXO3 Programming and Configuration Usage Guide for more information about using the dual-use pins as general purpose I/Os.

Lattice design software uses proprietary compression technology to compress bit-streams for use in MachXO3L/ LF devices. Use of this technology allows Lattice to provide a lower cost solution. In the unlikely event that this technology is unable to compress bitstreams to fit into the amount of on-chip NVCM/Flash, there are a variety of techniques that can be utilized to allow the bitstream to fit in the on-chip NVCM/Flash. For more details, refer to TN1279, MachXO3 Programming and Configuration Usage Guide.

The Test Access Port (TAP) has five dual purpose pins (TDI, TDO, TMS, TCK and JTAGENB). These pins are dual function pins - TDI, TDO, TMS and TCK can be used as general purpose I/O if desired. For more details, refer to TN1279, MachXO3 Programming and Configuration Usage Guide.

### TransFR (Transparent Field Reconfiguration)

TransFR is a unique Lattice technology that allows users to update their logic in the field without interrupting system operation using a simple push-button solution. For more details refer to TN1087, Minimizing System Interruption During Configuration Using TransFR Technology for details.



## MachXO3 Family Data Sheet DC and Switching Characteristics

#### February 2017

#### Advance Data Sheet DS1047

### Absolute Maximum Ratings<sup>1, 2, 3</sup>

	MachXO3L/LF E (1.2 V)	MachXO3L/LF C (2.5 V/3.3 V)
Supply Voltage V <sub>CC</sub>	$\ldots$ .–0.5 V to 1.32 V $\ldots$ .	–0.5 V to 3.75 V
Output Supply Voltage V <sub>CCIO</sub>	–0.5 V to 3.75 V	–0.5 V to 3.75 V
I/O Tri-state Voltage Applied <sup>4, 5</sup>	–0.5 V to 3.75 V	–0.5 V to 3.75 V
Dedicated Input Voltage Applied <sup>4</sup>	–0.5 V to 3.75 V	–0.5 V to 3.75 V
Storage Temperature (Ambient)	–55 °C to 125 °C	–55 °C to 125 °C
Junction Temperature (T <sub>1</sub> )	–40 °C to 125 °C	–40 °C to 125 °C

1. Stress above those listed under the "Absolute Maximum Ratings" may cause permanent damage to the device. Functional operation of the device at these or any other conditions above those indicated in the operational sections of this specification is not implied.

2. Compliance with the Lattice Thermal Management document is required.

3. All voltages referenced to GND.

4. Overshoot and undershoot of -2 V to (V<sub>IHMAX</sub> + 2) volts is permitted for a duration of <20 ns.

5. The dual function  $I^2C$  pins SCL and SDA are limited to -0.25 V to 3.75 V or to -0.3 V with a duration of <20 ns.

### **Recommended Operating Conditions**<sup>1</sup>

Symbol	Parameter		Max.	Units
V <sub>CC</sub> <sup>1</sup>	Core Supply Voltage for 1.2 V Devices	1.14	1.26	V
	Core Supply Voltage for 2.5 V/3.3 V Devices	2.375	3.465	V
V <sub>CCIO</sub> <sup>1, 2, 3</sup>	I/O Driver Supply Voltage	1.14	3.465	V
t <sub>JCOM</sub>	Junction Temperature Commercial Operation	0	85	°C
t <sub>JIND</sub>	Junction Temperature Industrial Operation	-40	100	°C

1. Like power supplies must be tied together. For example, if V<sub>CCIO</sub> and V<sub>CC</sub> are both the same voltage, they must also be the same supply.

2. See recommended voltages by I/O standard in subsequent table.

3. V<sub>CCIO</sub> pins of unused I/O banks should be connected to the V<sub>CC</sub> power supply on boards.

### Power Supply Ramp Rates<sup>1</sup>

	iyp.	wax.	Units
t <sub>RAMP</sub> Power supply ramp rates for all power supplies. 0.01	—	100	V/ms

1. Assumes monotonic ramp rates.

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### **DC Electrical Characteristics**

Symbol	Parameter	Condition	Min.	Тур.	Max.	Units
		Clamp OFF and $V_{CCIO} < V_{IN} < V_{IH}$ (MAX)			+175	μΑ
		Clamp OFF and $V_{IN} = V_{CCIO}$	-10	—	10	μΑ
I <sub>IL</sub> , I <sub>IH</sub> <sup>1, 4</sup>	Input or I/O Leakage	Clamp OFF and V <sub>CCIO</sub> - 0.97 V < V <sub>IN</sub> < V <sub>CCIO</sub>	-175	_	—	μA
		Clamp OFF and 0 V < $V_{IN}$ < $V_{CCIO}$ - 0.97 V	_		10	μΑ
		Clamp OFF and V <sub>IN</sub> = GND	_		10	μΑ
		Clamp ON and 0 V < $V_{IN}$ < $V_{CCIO}$			10	μΑ
I <sub>PU</sub>	I/O Active Pull-up Current	0 < V <sub>IN</sub> < 0.7 V <sub>CCIO</sub>	-30		-309	μΑ
I <sub>PD</sub>	I/O Active Pull-down Current	V <sub>IL</sub> (MAX) < V <sub>IN</sub> < V <sub>CCIO</sub>	30	—	305	μA
I <sub>BHLS</sub>	Bus Hold Low sustaining current	$V_{IN} = V_{IL} (MAX)$	30	—	—	μA
I <sub>BHHS</sub>	Bus Hold High sustaining current	V <sub>IN</sub> = 0.7V <sub>CCIO</sub>	-30	_	_	μΑ
I <sub>BHLO</sub>	Bus Hold Low Overdrive current	$0 \leq V_{IN} \leq V_{CCIO}$	_	—	305	μΑ
І <sub>внно</sub>	Bus Hold High Overdrive current	$0 \leq V_{IN} \leq V_{CCIO}$	_	_	-309	μΑ
V <sub>BHT</sub> <sup>3</sup>	Bus Hold Trip Points		V <sub>IL</sub> (MAX)	—	V <sub>IH</sub> (MIN)	V
C1	I/O Capacitance <sup>2</sup>	$V_{CCIO} = 3.3 V, 2.5 V, 1.8 V, 1.5 V, 1.2 V, V_{CC} = Typ., V_{IO} = 0 to V_{IH} (MAX)$	3	5	9	pf
C2	Dedicated Input Capacitance <sup>2</sup>	$V_{CCIO} = 3.3 V, 2.5 V, 1.8 V, 1.5 V, 1.2 V, V_{CC} = Typ., V_{IO} = 0 to V_{IH} (MAX)$	3	5.5	7	pf
		V <sub>CCIO</sub> = 3.3 V, Hysteresis = Large	_	450	—	mV
		V <sub>CCIO</sub> = 2.5 V, Hysteresis = Large		250	—	mV
		V <sub>CCIO</sub> = 1.8 V, Hysteresis = Large		125	—	mV
V	Hysteresis for Schmitt	V <sub>CCIO</sub> = 1.5 V, Hysteresis = Large	_	100	_	mV
VHYST	Trigger Inputs <sup>5</sup>	V <sub>CCIO</sub> = 3.3 V, Hysteresis = Small	_	250	_	mV
		V <sub>CCIO</sub> = 2.5 V, Hysteresis = Small	_	150	_	mV
		V <sub>CCIO</sub> = 1.8 V, Hysteresis = Small	—	60	—	mV
		V <sub>CCIO</sub> = 1.5 V, Hysteresis = Small	_	40	—	mV

1. Input or I/O leakage current is measured with the pin configured as an input or as an I/O with the output driver tri-stated. It is not measured with the output driver active. Bus maintenance circuits are disabled.

2. T<sub>A</sub> 25 °C, f = 1.0 MHz.

3. Please refer to V<sub>IL</sub> and V<sub>IH</sub> in the sysIO Single-Ended DC Electrical Characteristics table of this document.

 When V<sub>IH</sub> is higher than V<sub>CCIO</sub>, a transient current typically of 30 ns in duration or less with a peak current of 6mA can occur on the high-tolow transition. For true LVDS output pins in MachXO3L/LF devices, V<sub>IH</sub> must be less than or equal to V<sub>CCIO</sub>.

5. With bus keeper circuit turned on. For more details, refer to TN1280, MachXO3 sysIO Usage Guide.



## Static Supply Current – C/E Devices<sup>1, 2, 3, 6</sup>

Symbol	Parameter	Device	Typ.⁴	Units
I <sub>CC</sub>	Core Power Supply	LCMXO3L/LF-1300C 256 Ball Package	4.8	mA
		LCMXO3L/LF-2100C	4.8	mA
		LCMXO3L/LF-2100C 324 Ball Package	8.45	mA
		LCMXO3L/LF-4300C	8.45	mA
		LCMXO3L/LF-4300C 400 Ball Package	12.87	mA
		LCMXO3L/LF-6900C <sup>7</sup>	12.87	mA
		LCMXO3L/LF-9400C <sup>7</sup>	17.86	mA
		LCMXO3L/LF-640E	1.00	mA
		LCMXO3L/LF-1300E	1.00	mA
		LCMXO3L/LF-1300E 256 Ball Package	1.39	mA
		LCMXO3L/LF-2100E	1.39	mA
		LCMXO3L/LF-2100E 324 Ball Package	2.55	mA
		LCMXO3L/LF-4300E	2.55	mA
		LCMXO3L/LF-6900E	4.06	mA
		LCMXO3L/LF-9400E	5.66	mA
I <sub>CCIO</sub>	Bank Power Supply <sup>5</sup> VCCIO = 2.5 V	All devices	0	mA

1. For further information on supply current, please refer to TN1289, Power Estimation and Management for MachXO3 Devices.

2. Assumes blank pattern with the following characteristics: all outputs are tri-stated, all inputs are configured as LVCMOS and held at V<sub>CCIO</sub> or GND, on-chip oscillator is off, on-chip PLL is off.

3. Frequency = 0 MHz.

4.  $T_J = 25$  °C, power supplies at nominal voltage.

5. Does not include pull-up/pull-down.

6. To determine the MachXO3L/LF peak start-up current data, use the Power Calculator tool.

7. Determination of safe ambient operating conditions requires use of the Diamond Power Calculator tool.



### LVPECL

The MachXO3L/LF family supports the differential LVPECL standard through emulation. This output standard is emulated using complementary LVCMOS outputs in conjunction with resistors across the driver outputs on all the devices. The LVPECL input standard is supported by the LVDS differential input buffer. The scheme shown in Differential LVPECL is one possible solution for point-to-point signals.

### Figure 3-3. Differential LVPECL



### Table 3-3. LVPECL DC Conditions<sup>1</sup>

Symbol	mbol Description Nominal		Units
Z <sub>OUT</sub>	Output impedance	20	Ohms
R <sub>S</sub>	Driver series resistor	93	Ohms
R <sub>P</sub>	Driver parallel resistor	196	Ohms
R <sub>T</sub>	Receiver termination	100	Ohms
V <sub>OH</sub>	Output high voltage	2.05	V
V <sub>OL</sub>	Output low voltage	1.25	V
V <sub>OD</sub>	Output differential voltage	0.80	V
V <sub>CM</sub>	Output common mode voltage	1.65	V
Z <sub>BACK</sub>	Back impedance	100.5	Ohms
I <sub>DC</sub>	DC output current	12.11	mA

#### **Over Recommended Operating Conditions**

1. For input buffer, see LVDS table.

For further information on LVPECL, BLVDS and other differential interfaces please see details of additional technical documentation at the end of the data sheet.



### MIPI D-PHY Emulation

MachXO3L/LF devices can support MIPI D-PHY unidirectional HS (High Speed) and bidirectional LP (Low Power) inputs and outputs via emulation. In conjunction with external resistors High Speed IOs use the LVDS25E buffer and Low Power IOs use the LVCMOS buffers. The scheme shown in Figure 3-4 is one possible solution for MIPI D-PHY Receiver implementation. The scheme shown in Figure 3-5 is one possible solution for MIPI D-PHY Transmitter implementation.

### Figure 3-4. MIPI D-PHY Input Using External Resistors



Table 3-4. MIPI DC Conditions<sup>1</sup>

	Description	Min.	Тур.	Max.	Units
Receiver	·				
External Terminatio	n				
RT	1% external resistor with VCCIO=2.5 V		50	—	Ohms
	1% external resistor with VCCIO=3.3 V	—	50	—	Ohms
High Speed					
VCCIO	VCCIO of the Bank with LVDS Emulated input buffer	—	2.5	—	V
	VCCIO of the Bank with LVDS Emulated input buffer	—	3.3	—	V
VCMRX	Common-mode voltage HS receive mode	150	200	250	mV
VIDTH	Differential input high threshold	—	—	100	mV
VIDTL	Differential input low threshold	-100	—	—	mV
VIHHS	Single-ended input high voltage		—	300	mV
VILHS	Single-ended input low voltage	100	—	—	mV
ZID	Differential input impedance	80	100	120	Ohms



### Typical Building Block Function Performance – C/E Devices<sup>1</sup>

### Pin-to-Pin Performance (LVCMOS25 12 mA Drive)

Function	–6 Timing	Units
Basic Functions		
16-bit decoder	8.9	ns
4:1 MUX	7.5	ns
16:1 MUX	8.3	ns

### **Register-to-Register Performance**

Function	–6 Timing	Units
Basic Functions	•	
16:1 MUX	412	MHz
16-bit adder	297	MHz
16-bit counter	324	MHz
64-bit counter	161	MHz
Embedded Memory Functions		
1024x9 True-Dual Port RAM (Write Through or Normal, EBR output registers)	183	MHz
Distributed Memory Functions		
16x4 Pseudo-Dual Port RAM (one PFU)	500	MHz

 The above timing numbers are generated using the Diamond design tool. Exact performance may vary with device and tool version. The tool uses internal parameters that have been characterized but are not tested on every device. Commercial timing numbers are shown at 85 °C and 1.14 V. Other operating conditions, including industrial, can be extracted from the Diamond software.

### **Derating Logic Timing**

Logic timing provided in the following sections of the data sheet and the Lattice design tools are worst case numbers in the operating range. Actual delays may be much faster. Lattice design tools can provide logic timing numbers at a particular temperature and voltage.



### DC and Switching Characteristics MachXO3 Family Data Sheet

			-6		-5		
Description	Device	Min.	Max.	Min.	Max.	Units	
Generic DDRX4 Outputs with Clock and Data Centered at Pin Using PCLK Pin for Clock Input – GDDRX4_TX.ECLK.Centered <sup>8, 9</sup>							
Output Data Valid Before CLK Output		0.455		0.570		ns	
Output Data Valid After CLK Output		0.455	—	0.570	_	ns	
DDRX4 Serial Output Data Speed	MachXO3L/LF devices,	—	800	—	630	Mbps	
DDRX4 ECLK Frequency (minimum limited by PLL)	top side only	_	400	_	315	MHz	
SCLK Frequency	-		100		79	MHz	
Itputs – GDDR71_TX.ECLK.7:1 <sup>8, 9</sup>							
Output Data Invalid Before CLK Output			0.160	_	0.180	ns	
Output Data Invalid After CLK Output			0.160		0.180	ns	
DDR71 Serial Output Data Speed	MachXO3L/LF devices,		756		630	Mbps	
DDR71 ECLK Frequency	top side only	_	378	—	315	MHz	
7:1 Output Clock Frequency (SCLK) (mini- mum limited by PLL)		_	108	_	90	MHz	
MIPI D-PHY Outputs with Clock and Data Centered at Pin Using PCLK Pin for Clock Input - GDDRX4_TX.ECLK.Centered <sup>10, 11, 12</sup>							
Output Data Valid Before CLK Output		0.200	—	0.200	_	UI	
Output Data Valid After CLK Output		0.200	—	0.200	_	UI	
MIPI D-PHY Output Data Speed	All MachXO3L/LF	_	900	_	900	Mbps	
MIPI D-PHY ECLK Frequency (minimum limited by PLL)	devices, top side only	_	450	_	450	MHz	
SCLK Frequency	<u> </u>	—	112.5	—	112.5	MHz	
	Description RX4 Outputs with Clock and Data Centered CECLK.Centered <sup>8, 9</sup> Output Data Valid Before CLK Output Output Data Valid After CLK Output DDRX4 Serial Output Data Speed DDRX4 ECLK Frequency (minimum limited by PLL) SCLK Frequency ttputs – GDDR71_TX.ECLK.7:1 <sup>8, 9</sup> Output Data Invalid Before CLK Output Output Data Invalid After CLK Output DDR71 Serial Output Data Speed DDR71 ECLK Frequency 7:1 Output Clock Frequency (SCLK) (mini- mum limited by PLL) Outputs with Clock and Data Centered at P C.ECLK.Centered <sup>10, 11, 12</sup> Output Data Valid Before CLK Output Output Data Valid After CLK Output MIPI D-PHY Output Data Speed MIPI D-PHY ECLK Frequency (minimum limited by PLL) SCLK Frequency	DescriptionDeviceRX4 Outputs with Clock and Data Centered at Pin Using PCLK Pin for C.ECLK.Centered <sup>8, 9</sup> In Using PCLK Pin for C.ECLK.Centered <sup>8, 9</sup> Output Data Valid Before CLK OutputMachXO3L/LF devices, top side onlyDDRX4 Serial Output Data SpeedMachXO3L/LF devices, top side onlyDDRX4 ECLK Frequency (minimum limited by PLL)MachXO3L/LF devices, top side onlySCLK FrequencyOutput Data Invalid Before CLK OutputOutput Data Invalid After CLK OutputMachXO3L/LF devices, top side onlyOutput Data Invalid After CLK OutputMachXO3L/LF devices, top side onlyDDR71 Serial Output Data SpeedMachXO3L/LF devices, top side onlyDDR71 ECLK Frequency 7:1 Output Clock Frequency (SCLK) (mini- mum limited by PLL)MachXO3L/LF devices, top side onlyOutput Data Valid Before CLK OutputOutput Data Valid Before CLK OutputOutput Data Valid Before CLK OutputAll MachXO3L/LF devices, top side onlyOutput Data Valid After CLK OutputAll MachXO3L/LF devices, top side onlyMIPI D-PHY Output Data SpeedAll MachXO3L/LF devices, top side onlyMIPI D-PHY ECLK Frequency (minimum limited by PLL)All MachXO3L/LF devices, top side onlySCLK FrequencyAll MachXO3L/LF devices, top side only	Description         Device         Min.           RX4 Outputs with Clock and Data Centered at Pin Using PCLK Pin for Clock (LECLK.Centered <sup>8,9</sup> )         0.455           Output Data Valid Before CLK Output         0.455           DDRX4 Serial Output Data Speed         MachXO3L/LF devices, top side only            DDRX4 ECLK Frequency (minimum limited by PLL)         MachXO3L/LF devices, top side only            SCLK Frequency             Output Data Invalid Before CLK Output             Output Data Invalid Before CLK Output             Output Data Invalid Before CLK Output             Output Data Invalid After CLK Output             DDR71 Serial Output Data Speed         MachXO3L/LF devices, top side only            DDR71 ECLK Frequency              Output Clock Frequency (SCLK) (minimum limited by PLL)              Output Data Valid After CLK Output              Output Data Valid Before CLK Output              Output Data Valid After CLK Output         0.200         0.200         0.200           Output Data Valid After CLK Out	-6Min.Max.RX4 Outputs with Clock and Data Centered at Pin Using PCLK Pin for Clock Input - CLECLK.Centered <sup>8, 9</sup> Output Data Valid Before CLK Output0.455Output Data Valid After CLK OutputMachXO3L/LF devices, top side only0.455DDRX4 ECLK Frequency (minimum limited by PLL)MachXO3L/LF devices, top side only800SCLK Frequency (minimum limited by PLL)100400Output Data Invalid Before CLK Output0.160Output Data Invalid After CLK Output0.160DDR71 Serial Output Data Speed DDR71 Serial Output Data SpeedMachXO3L/LF devices, top side only108Output Swith Clock and Data Centered at Pin Using PCLK Pin for Clock Input - t.ECLK.Centered <sup>10, 11, 12</sup> 0.200Output Data Valid Before CLK Output DDR71 Serial Output Data SpeedAll MachXO3L/LF devices, top side only0.200Output Data Valid After CLK Output Mup PLL)All MachXO3L/LF devices, top side only0.200MIPI D-PHY Output Data Speed MIPI D-PHY CLK Frequency (minimum limited by PLL)All MachXO3L/LF devices, top side only450MIPI D-PHY ECLK Frequency (minimum limited by PLL)450450	Description         Image: Description         Image: Description         Max.         Min.         Max.         Min.           RX4 Outputs with Clock and Data Centered at Pin Using PCLK Pin for Clock Input - LECLK.Centered <sup>8, 9</sup> 0.455         -         0.570           Output Data Valid Before CLK Output         MachXO3L/LF devices, top side only         0.455         -         0.570           DDRX4 Serial Output Data Speed         MachXO3L/LF devices, top side only         -         800         -           DDRX4 ECLK Frequency (minimum limited by PLL)         MachXO3L/LF devices, top side only         -         400         -           SCLK Frequency         -         0.160         -	Description         Device         Min.         Max.         Min.         Max.           RX4 Outputs with Clock and Data Centered at Pin Using PCLK Pin for Clock Input - LECLK.Centered <sup>9,9</sup> 0.455         -         0.570         -           Output Data Valid Before CLK Output         MachXO3L/LF devices, top side only         0.455         -         0.570         -           DDRX4 Serial Output Data Speed         MachXO3L/LF devices, top side only         0.455         -         0.570         -           DDRX4 ECLK Frequency (minimum limited by PLL)         MachXO3L/LF devices, top side only         -         800         -         630           SCLK Frequency         -         0.160         -         916         -         916           Output Data Invalid Before CLK Output         MachXO3L/LF devices, top side only         -         0.160         -         0.180           DDR71 ECLK Frequency         MachXO3L/LF devices, top side only         -         756         -         630           DDR71 ECLK Frequency         MachXO3L/LF devices, top side only         -         756         -         630           DDR71 ECLK Frequency         MachXO3L/LF devices, top side only         -         108         -         90           Output Data Valid After CLK Output         MachXO3L/LF	

1. Exact performance may vary with device and design implementation. Commercial timing numbers are shown at 85 °C and 1.14 V. Other operating conditions, including industrial, can be extracted from the Diamond software.

2. General I/O timing numbers based on LVCMOS 2.5, 8 mA, 0pf load, fast slew rate.

3. Generic DDR timing numbers based on LVDS I/O (for input, output, and clock ports).

4. 7:1 LVDS (GDDR71) uses the LVDS I/O standard (for input, output, and clock ports).

5. For Generic DDRX1 mode  $t_{SU} = t_{HO} = (t_{DVE} - t_{DVA} - 0.03 \text{ ns})/2$ .

6. The t<sub>SU DEL</sub> and t<sub>H DEL</sub> values use the SCLK\_ZERHOLD default step size. Each step is 105 ps (-6), 113 ps (-5), 120 ps (-4).

7. This number for general purpose usage. Duty cycle tolerance is +/-10%.

8. Duty cycle is  $\pm -5\%$  for system usage.

9. Performance is calculated with 0.225 UI.

10. Performance is calculated with 0.20 UI.

11. Performance for Industrial devices are only supported with VCC between 1.16 V to 1.24 V.

12. Performance for Industrial devices and -5 devices are not modeled in the Diamond design tool.

13. The above timing numbers are generated using the Diamond design tool. Exact performance may vary with the device selected.

14. Above 800 Mbps is only supported with WLCSP and csfBGA packages

15. Between 800 Mbps to 900 Mbps:

a. VIDTH exceeds the MIPI D-PHY Input DC Conditions Table 3-4 and can be calculated with the equation tSU or tH = -0.0005\*VIDTH + 0.3284

b. Example calculations

i. tSU and tHO = 0.28 with VIDTH = 100 mV

ii. tSU and tHO = 0.25 with VIDTH = 170 mV

iii. tSU and tHO = 0.20 with VIDTH = 270 mV



		MachXO3L/LF-2100					
	WLCSP49	CSFBGA121	CSFBGA256	CSFBGA324	CABGA256	CABGA324	
General Purpose IO per Bank		•	•			•	
Bank 0	19	24	50	71	50	71	
Bank 1	0	26	52	62	52	68	
Bank 2	13	26	52	72	52	72	
Bank 3	0	7	16	22	16	24	
Bank 4	0	7	16	14	16	16	
Bank 5	6	10	20	27	20	28	
Total General Purpose Single Ended IO	38	100	206	268	206	279	
Differential IO per Bank							
Bank 0	10	12	25	36	25	36	
Bank 1	0	13	26	30	26	34	
Bank 2	6	13	26	36	26	36	
Bank 3	0	3	8	10	8	12	
Bank 4	0	3	8	6	8	8	
Bank 5	3	5	10	13	10	14	
Total General Purpose Differential IO	19	49	103	131	103	140	
Dual Function IO	25	33	33	37	33	37	
Number 7:1 or 8:1 Gearboxes						•	
Number of 7:1 or 8:1 Output Gearbox Available (Bank 0)	5	7	14	18	14	18	
Number of 7:1 or 8:1 Input Gearbox Available (Bank 2)	6	13	14	18	14	18	
High-speed Differential Outputs						•	
Bank 0	5	7	14	18	14	18	
VCCIO Pins		•	•			•	
Bank 0	2	1	4	4	4	4	
Bank 1	0	1	3	4	4	4	
Bank 2	1	1	4	4	4	4	
Bank 3	0	1	2	2	1	2	
Bank 4	0	1	2	2	2	2	
Bank 5	1	1	2	2	1	2	
VCC	2	4	8	8	8	10	
GND	4	10	24	16	24	16	
NC	0	0	0	13	1	0	
Reserved for Configuration	1	1	1	1	1	1	
Total Count of Bonded Pins	49	121	256	324	256	324	



## MachXO3 Family Data Sheet Ordering Information

May 2016

Advance Data Sheet DS1047

### MachXO3 Part Number Description



### **Ordering Information**

MachXO3L/LF devices have top-side markings as shown in the examples below, on the 256-Ball caBGA package with MachXO3-6900 device in Commercial Temperature in Speed Grade 5. Notice that for the MachXO3LF device, *LMXO3LF* is used instead of *LCMXO3LF* as in the Part Number.



with LMXO3LF

Note: Markings are abbreviated for small packages.

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# MachXO3L Ultra Low Power Commercial and Industrial Grade Devices, Halogen Free (RoHS) Packaging

Part Number	LUTs	Supply Voltage	Speed	Package	Leads	Temp.
LCMXO3L-640E-5MG121C	640	1.2 V	5	Halogen-Free csfBGA	121	COM
LCMXO3L-640E-6MG121C	640	1.2 V	6	Halogen-Free csfBGA	121	COM
LCMXO3L-640E-5MG121I	640	1.2 V	5	Halogen-Free csfBGA	121	IND
LCMXO3L-640E-6MG121I	640	1.2 V	6	Halogen-Free csfBGA	121	IND

Part Number	LUTs	Supply Voltage	Speed	Package	Leads	Temp.
LCMXO3L-1300E-5UWG36CTR	1300	1.2 V	5	Halogen-Free WLCSP	36	COM
LCMXO3L-1300E-5UWG36CTR50	1300	1.2 V	5	Halogen-Free WLCSP	36	COM
LCMXO3L-1300E-5UWG36CTR1K	1300	1.2 V	5	Halogen-Free WLCSP	36	COM
LCMXO3L-1300E-5UWG36ITR	1300	1.2 V	5	Halogen-Free WLCSP	36	IND
LCMXO3L-1300E-5UWG36ITR50	1300	1.2 V	5	Halogen-Free WLCSP	36	IND
LCMXO3L-1300E-5UWG36ITR1K	1300	1.2 V	5	Halogen-Free WLCSP	36	IND
LCMXO3L-1300E-5MG121C	1300	1.2 V	5	Halogen-Free csfBGA	121	COM
LCMXO3L-1300E-6MG121C	1300	1.2 V	6	Halogen-Free csfBGA	121	COM
LCMXO3L-1300E-5MG1211	1300	1.2 V	5	Halogen-Free csfBGA	121	IND
LCMXO3L-1300E-6MG1211	1300	1.2 V	6	Halogen-Free csfBGA	121	IND
LCMXO3L-1300E-5MG256C	1300	1.2 V	5	Halogen-Free csfBGA	256	COM
LCMXO3L-1300E-6MG256C	1300	1.2 V	6	Halogen-Free csfBGA	256	COM
LCMXO3L-1300E-5MG256I	1300	1.2 V	5	Halogen-Free csfBGA	256	IND
LCMXO3L-1300E-6MG256I	1300	1.2 V	6	Halogen-Free csfBGA	256	IND
LCMXO3L-1300C-5BG256C	1300	2.5 V / 3.3 V	5	Halogen-Free caBGA	256	COM
LCMXO3L-1300C-6BG256C	1300	2.5 V / 3.3 V	6	Halogen-Free caBGA	256	COM
LCMXO3L-1300C-5BG256I	1300	2.5 V / 3.3 V	5	Halogen-Free caBGA	256	IND
LCMXO3L-1300C-6BG256I	1300	2.5 V / 3.3 V	6	Halogen-Free caBGA	256	IND

Part Number	LUTs	Supply Voltage	Speed	Package	Leads	Temp.
LCMXO3L-2100E-5UWG49CTR	2100	1.2 V	5	Halogen-Free WLCSP	49	COM
LCMXO3L-2100E-5UWG49CTR50	2100	1.2 V	5	Halogen-Free WLCSP	49	COM
LCMXO3L-2100E-5UWG49CTR1K	2100	1.2 V	5	Halogen-Free WLCSP	49	COM
LCMXO3L-2100E-5UWG49ITR	2100	1.2 V	5	Halogen-Free WLCSP	49	IND
LCMXO3L-2100E-5UWG49ITR50	2100	1.2 V	5	Halogen-Free WLCSP	49	IND
LCMXO3L-2100E-5UWG49ITR1K	2100	1.2 V	5	Halogen-Free WLCSP	49	IND
LCMXO3L-2100E-5MG121C	2100	1.2 V	5	Halogen-Free csfBGA	121	COM
LCMXO3L-2100E-6MG121C	2100	1.2 V	6	Halogen-Free csfBGA	121	COM
LCMXO3L-2100E-5MG121I	2100	1.2 V	5	Halogen-Free csfBGA	121	IND
LCMXO3L-2100E-6MG1211	2100	1.2 V	6	Halogen-Free csfBGA	121	IND
LCMXO3L-2100E-5MG256C	2100	1.2 V	5	Halogen-Free csfBGA	256	COM
LCMXO3L-2100E-6MG256C	2100	1.2 V	6	Halogen-Free csfBGA	256	COM
LCMXO3L-2100E-5MG256I	2100	1.2 V	5	Halogen-Free csfBGA	256	IND
LCMXO3L-2100E-6MG256I	2100	1.2 V	6	Halogen-Free csfBGA	256	IND
CMXO3L-2100E-5MG324C 2100		1.2 V	5	Halogen-Free csfBGA	324	COM
LCMXO3L-2100E-6MG324C	2100	1.2 V	6	Halogen-Free csfBGA	324	COM
LCMXO3L-2100E-5MG324I	2100	1.2 V	5	Halogen-Free csfBGA	324	IND



Part Number	LUTs	Supply Voltage	Speed	Package	Leads	Temp.
LCMXO3LF-2100E-6MG324I	2100	1.2 V	6	Halogen-Free csfBGA	324	IND
LCMXO3LF-2100C-5BG256C	2100	2.5 V / 3.3 V	5	Halogen-Free caBGA	256	СОМ
LCMXO3LF-2100C-6BG256C	2100	2.5 V / 3.3 V	6	Halogen-Free caBGA	256	COM
LCMXO3LF-2100C-5BG256I	2100	2.5 V / 3.3 V	5	Halogen-Free caBGA	256	IND
LCMXO3LF-2100C-6BG256I	2100	2.5 V / 3.3 V	6	Halogen-Free caBGA	256	IND
LCMXO3LF-2100C-5BG324C	2100	2.5 V / 3.3 V	5	Halogen-Free caBGA	324	COM
LCMXO3LF-2100C-6BG324C	2100	2.5 V / 3.3 V	6	Halogen-Free caBGA	324	COM
LCMXO3LF-2100C-5BG324I	2100	2.5 V / 3.3 V	5	Halogen-Free caBGA	324	IND
LCMXO3LF-2100C-6BG324I	2100	2.5 V / 3.3 V	6	Halogen-Free caBGA	324	IND
Part Number	LUTs	Supply Voltage	Speed	Package	Leads	Temp.
LCMXO3LF-4300E-5UWG81CTR	4300	1.2 V	5	Halogen-Free WLCSP	81	COM
LCMXO3LF-4300E-5UWG81CTR50	4300	1.2 V	5	Halogen-Free WLCSP	81	COM
LCMXO3LF-4300E-5UWG81CTR1K	4300	1.2 V	5	Halogen-Free WLCSP	81	COM
LCMXO3LF-4300E-5UWG81ITR	4300	1.2 V	5	Halogen-Free WLCSP	81	IND
LCMXO3LF-4300E-5UWG81ITR50	4300	1.2 V	5	Halogen-Free WLCSP	81	IND
LCMXO3LF-4300E-5UWG81ITR1K	4300	1.2 V	5	Halogen-Free WLCSP	81	IND
LCMXO3LF-4300E-5MG121C	4300	1.2 V	5	Halogen-Free csfBGA	121	COM
LCMXO3LF-4300E-6MG121C	4300	1.2 V	6	Halogen-Free csfBGA	121	COM
LCMXO3LF-4300E-5MG121I	4300	1.2 V	5	Halogen-Free csfBGA	121	IND
LCMXO3LF-4300E-6MG121I	4300	1.2 V	6	Halogen-Free csfBGA	121	IND
LCMXO3LF-4300E-5MG256C	4300	1.2 V	5	Halogen-Free csfBGA	256	COM
LCMXO3LF-4300E-6MG256C	4300	1.2 V	6	Halogen-Free csfBGA	256	COM
LCMXO3LF-4300E-5MG256I	4300	1.2 V	5	Halogen-Free csfBGA	256	IND
LCMXO3LF-4300E-6MG256I	4300	1.2 V	6	Halogen-Free csfBGA	256	IND
LCMXO3LF-4300E-5MG324C	4300	1.2 V	5	Halogen-Free csfBGA	324	COM
LCMXO3LF-4300E-6MG324C	4300	1.2 V	6	Halogen-Free csfBGA	324	COM
LCMXO3LF-4300E-5MG324I	4300	1.2 V	5	Halogen-Free csfBGA	324	IND
LCMXO3LF-4300E-6MG324I	4300	1.2 V	6	Halogen-Free csfBGA	324	IND
LCMXO3LF-4300C-5BG256C	4300	2.5 V / 3.3 V	5	Halogen-Free caBGA	256	COM
LCMXO3LF-4300C-6BG256C	4300	2.5 V / 3.3 V	6	Halogen-Free caBGA	256	COM
LCMXO3LF-4300C-5BG256I	4300	2.5 V / 3.3 V	5	Halogen-Free caBGA	256	IND
LCMXO3LF-4300C-6BG256I	4300	2.5 V / 3.3 V	6	Halogen-Free caBGA	256	IND
LCMXO3LF-4300C-5BG324C	4300	2.5 V / 3.3 V	5	Halogen-Free caBGA	324	COM
LCMXO3LF-4300C-6BG324C	4300	2.5 V / 3.3 V	6	Halogen-Free caBGA	324	COM
LCMXO3LF-4300C-5BG324I	4300	2.5 V / 3.3 V	5	Halogen-Free caBGA	324	IND
LCMXO3LF-4300C-6BG324I	4300	2.5 V / 3.3 V	6	Halogen-Free caBGA	324	IND
LCMXO3LF-4300C-5BG400C	4300	2.5 V / 3.3 V	5	Halogen-Free caBGA	400	COM
LCMXO3LF-4300C-6BG400C	4300	2.5 V / 3.3 V	6	Halogen-Free caBGA	400	COM
LCMXO3LF-4300C-5BG400I	4300	2.5 V / 3.3 V	5	Halogen-Free caBGA	400	IND
LCMXO3LF-4300C-6BG400I	4300	2.5 V / 3.3 V	6	Halogen-Free caBGA	400	IND



Part Number	LUTs	Supply Voltage	Speed	Package	Leads	Temp.
LCMXO3LF-6900E-5MG256C	6900	1.2 V	5	Halogen-Free csfBGA	256	СОМ
LCMXO3LF-6900E-6MG256C	6900	1.2 V	6	Halogen-Free csfBGA	256	COM
LCMXO3LF-6900E-5MG256I	6900	1.2 V	5	Halogen-Free csfBGA	256	IND
LCMXO3LF-6900E-6MG256I	6900	1.2 V	6	Halogen-Free csfBGA	256	IND
LCMXO3LF-6900E-5MG324C	6900	1.2 V	5	Halogen-Free csfBGA	324	СОМ
LCMXO3LF-6900E-6MG324C	6900	1.2 V	6	Halogen-Free csfBGA	324	СОМ
LCMXO3LF-6900E-5MG324I	6900	1.2 V	5	Halogen-Free csfBGA	324	IND
LCMXO3LF-6900E-6MG324I	6900	1.2 V	6	Halogen-Free csfBGA	324	IND
LCMXO3LF-6900C-5BG256C	6900	2.5 V / 3.3 V	5	Halogen-Free caBGA	256	COM
LCMXO3LF-6900C-6BG256C	6900	2.5 V / 3.3 V	6	Halogen-Free caBGA	256	COM
LCMXO3LF-6900C-5BG256I	6900	2.5 V / 3.3 V	5	Halogen-Free caBGA	256	IND
LCMXO3LF-6900C-6BG256I	6900	2.5 V / 3.3 V	6	Halogen-Free caBGA	256	IND
LCMXO3LF-6900C-5BG324C	6900	2.5 V / 3.3 V	5	Halogen-Free caBGA	324	COM
LCMXO3LF-6900C-6BG324C	6900	2.5 V / 3.3 V	6	Halogen-Free caBGA	324	COM
LCMXO3LF-6900C-5BG324I	6900	2.5 V / 3.3 V	5	Halogen-Free caBGA	324	IND
LCMXO3LF-6900C-6BG324I	6900	2.5 V / 3.3 V	6	Halogen-Free caBGA	324	IND
LCMXO3LF-6900C-5BG400C	6900	2.5 V / 3.3 V	5	Halogen-Free caBGA	400	COM
LCMXO3LF-6900C-6BG400C	6900	2.5 V / 3.3 V	6	Halogen-Free caBGA	400	COM
LCMXO3LF-6900C-5BG400I	6900	2.5 V / 3.3 V	5	Halogen-Free caBGA	400	IND
LCMXO3LF-6900C-6BG400I	6900	2.5 V / 3.3 V	6	Halogen-Free caBGA	400	IND
	T		<b></b>	1	1	1
Part Number	LUTs	Supply Voltage	Speed	Package	Leads	Temp.
LCMXO3LF-9400E-5MG256C	9400	1.2 V	5	Halogen-Free csfBGA	256	COM
LCMXO3LF-9400E-6MG256C	9400	1.2 V	6	Halogen-Free csfBGA	256	COM
LCMXO3LF-9400E-5MG256I	9400	1.2 V	5	Halogen-Free csfBGA	256	IND
LCMXO3LF-9400E-6MG256I	9400	1.2 V	6	Halogen-Free csfBGA	256	IND
LCMXO3LF-9400C-5BG256C	9400	2.5 V/3.3 V	5	Halogen-Free caBGA	256	COM
LCMXO3LF-9400C-6BG256C	9400	2.5 V/3.3 V	6	Halogen-Free caBGA	256	COM
LCMXO3LF-9400C-5BG256I	9400	2.5 V/3.3 V	5	Halogen-Free caBGA	256	IND
LCMXO3LF-9400C-6BG256I	9400	2.5 V/3.3 V	6	Halogen-Free caBGA	256	IND
LCMXO3LF-9400C-5BG400C	9400	2.5 V/3.3 V	5	Halogen-Free caBGA	400	COM
LCMXO3LF-9400C-6BG400C	9400	2.5 V/3.3 V	6	Halogen-Free caBGA	400	COM
LCMXO3LF-9400C-5BG400I	9400	2.5 V/3.3 V	5	Halogen-Free caBGA	400	IND
LCMXO3LF-9400C-6BG400I	9400	2.5 V/3.3 V	6	Halogen-Free caBGA	400	IND
LCMXO3LF-9400C-5BG484C	9400	2.5 V/3.3 V	5	Halogen-Free caBGA	484	COM
LCMXO3LF-9400C-6BG484C	9400	2.5 V/3.3 V	6	Halogen-Free caBGA	484	COM
LCMXO3LF-9400C-5BG484I	9400	2.5 V/3.3 V	5	Halogen-Free caBGA	484	IND
LCMXO3LF-9400C-6BG484I	9400	2.5 V/3.3 V	6	Halogen-Free caBGA	484	IND



# MachXO3 Family Data Sheet Revision History

#### February 2017

Advance Data Sheet DS1047

Date	Version	Section	Change Summary
February 2017	1.8	Architecture	Updated Supported Standards section. Corrected "MDVS" to "MLDVS" in Table 2-11, Supported Input Standards.
		DC and Switching Characteristics	Updated ESD Performance section. Added reference to the MachXO2 Product Family Qualification Summary document.
			Updated Static Supply Current – C/E Devices section. Added footnote 7.
			Updated MachXO3L/LF External Switching Characteristics – C/E Devices section. — Populated values for MachXO3L/LF-9400. — Under 7:1 LVDS Outputs – GDDR71_TX.ECLK.7:1, corrected "t <sub>DVB</sub> " to "t <sub>DIB</sub> " and "t <sub>DVA</sub> " to "t <sub>DIA</sub> " and revised their descriptions. — Added Figure 3-6, Receiver GDDR71_RX Waveforms and Figure 3-7, Transmitter GDDR71_TX Waveforms.
		Pinout Information	Updated the Pin Information Summary section. Added MachXO3L/LF- 9600C packages.
May 2016	1.7	DC and Switching Characteristics	Updated Absolute Maximum Ratings section. Modified I/O Tri-state Volt- age Applied and Dedicated Input Voltage Applied footnotes.
			Updated sysIO Recommended Operating Conditions section. — Added standards. — Added V <sub>REF</sub> (V) — Added footnote 4.
			Updated sysIO Single-Ended DC Electrical Characteristics section. Added I/O standards.
		Ordering Information	Updated MachXO3L Ultra Low Power Commercial and Industrial Grade Devices, Halogen Free (RoHS) Packaging section. Added LCMXO3L-9400C part numbers.
			Updated MachXO3LF Ultra Low Power Commercial and Industrial Grade Devices, Halogen Free (RoHS) Packaging section. Added LCMXO3L-9400C part numbers.

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